

**M/A-COM Products** 

Released, 29 Jun 07

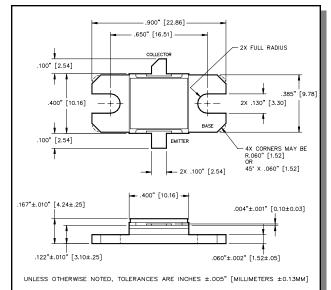
# Radar Pulsed Power Transistor 5W, 2.7-3.1 GHz, 100µs Pulse, 10% Duty

#### Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

1

### **Outline Drawing**



#### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V <sub>CES</sub>	65	V
Emitter-Base Voltage	V <sub>EBO</sub>	3.0	V
Collector Current (Peak)	Ι <sub>C</sub>	0.7	А
Power Dissipation @ +25°C	P <sub>TOT</sub>	50	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	TJ	200	°C

### Electrical Specifications: T<sub>c</sub> = 25 ± 5°C (Room Ambient )

Parameter	Test Conditions	Frequency	Symbol	Min	Мах	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA		BV <sub>CES</sub>	65	-	V
Collector-Emitter Leakage Current	$V_{CE} = 40V$		I <sub>CES</sub>	-	1.0	mA
Thermal Resistance	Vcc = 36V, Pin = 1.0W	F = 2.7, 2.9, 3.1 GHz	R <sub>TH(JC)</sub>	-	3.5	°C/W
Output Power	Vcc = 36V, Pin = 1.0W	F = 2.7, 2.9, 3.1 GHz	P <sub>OUT</sub>	5.0	-	W
Power Gain	Vcc = 36V, Pin = 1.0W	F = 2.7, 2.9, 3.1 GHz	G <sub>P</sub>	7.0	-	dB
Collector Efficiency	Vcc = 36V, Pin = 1.0W	F = 2.7, 2.9, 3.1 GHz	η <sub>c</sub>	30	-	%
Input Return Loss	Vcc = 36V, Pin = 1.0W	F = 2.7, 2.9, 3.1 GHz	RL	-	-6	dB
Load Mismatch Tolerance	Vcc = 36V, Pin = 1.0W	F = 2.7, 2.9, 3.1 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 36V, Pin = 1.0W	F = 2.7, 2.9, 3.1 GHz	VSWR-S	-	1.5:1	-

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

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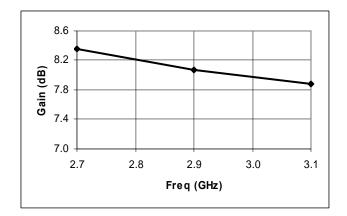


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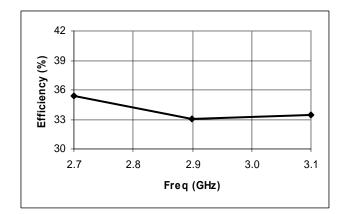
#### Typical RF Performance

Freq. (GHz)	Pin (W)	Pin (W)	Gain (dB)	lc (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
2.7	1.0	5.6	7.47	0.48	32.6	-12.8	S	Р
2.9	1.0	6.1	7.83	0.50	33.5	-16.7	S	Р
3.1	1.0	6.2	7.89	0.51	33.8	-20.5	S	Р

Gain vs. Frequency

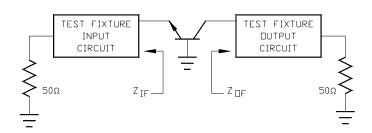


## **Collector Efficiency vs. Frequency**



#### **RF Test Fixture Impedance**

F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
2.7	40 - j12	25 + j3.5
2.9	35 - j16	16 + j2.4
3.1	30 - j18	12 + j4.0



2

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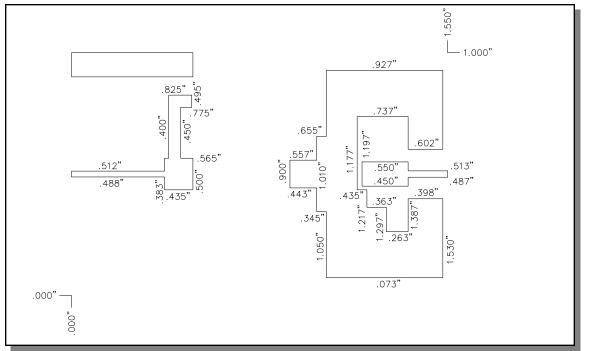
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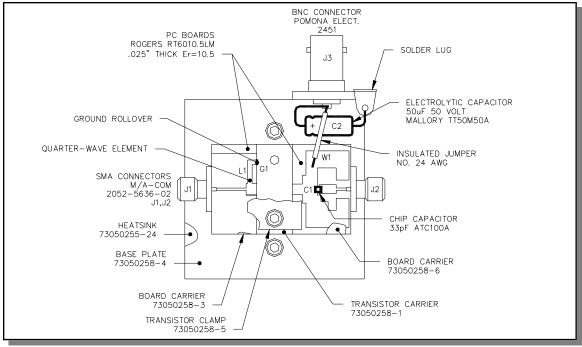
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## **Test Fixture Circuit Dimensions**



### **Test Fixture Assembly**



3

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